

#### INCHANGE SEMICONDUCTOR

# isc N-Channel MOSFET Transistor

## **IRFS7734**

#### • FEATURES

- With TO-263( D2PAK ) packaging
- High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

#### APPLICATIONS

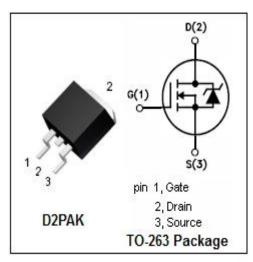
- Power supply
- Switching applications

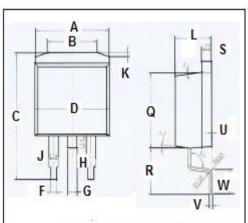
SYMBOL	PARAMETER	VALUE	UNIT					
V <sub>DSS</sub>	Drain-Source Voltage	75	V					
V <sub>GSS</sub>	Gate-Source Voltage	±20	∧v					
ID	Drain Current-Continuous;Tc=25°C Tc=100°C	183 130	A					
I <sub>DM</sub>	Drain Current-Single Pulsed	650	А					
PD	Total Dissipation	375	W					
Tj	Operating Junction Temperature	175	°C					
T <sub>stg</sub>	Storage Temperature	-55~175	°C					

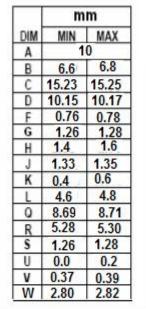
# • THERMAL CHARACTERISTICS

		AL CHARACTERISTICS		
	SYMBOL	PARAMETER	ARAMETER MAX UI	
Rth(ch-c) Channel-to-		Channel-to-case thermal resistance	0.51	°C/W
	Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C/W

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#### isc website: www.iscsemi.cn

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#### ELECTRICAL CHARACTERISTICS

 $T_{C}\text{=}25^{\circ}\!\!\!\!\mathrm{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =0.25mA	75			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	2.1		3.7	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =100A		2.8	3.5	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±20V;V <sub>DS</sub> = 0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =75V; V <sub>GS</sub> = 0V;Tc=25°C V <sub>DS</sub> =75V; V <sub>GS</sub> = 0V; Tc=125°C			1 150	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =100A, V <sub>GS</sub> = 0 V			1.2	V

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